

“Towards Straintronics: Guiding Excitons in 2D Materials” — CCNY & Partners Make Breakthrough

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From a team of City College of New York physicists and their collaborators in Japan and Germany comes another advancement in the study of excitons -- electrically neutral quasiparticles that exist in insulators, semi-conductors and some liquids. The researchers are announcing the creation of an "excitonic" wire, or one-dimensional channel for excitons. This in turn could result in innovative devices that could one day replace certain tasks that are now performed by standard transistor technology.

Florian Dirnberger, post-doc in Vinod Menon’s research group in CCNY’s Center for Discovery and Innovation, and one of the lead authors of the study that appears in the journal “[Science Advances](#),” detailed the team’s breakthrough. “Our main achievement was to manage to create these excitonic wires, essentially one-dimensional channels for excitons, in what is otherwise a two-dimensional semiconductor,” he said. “Since charge neutral excitons are not simply controlled by external voltages, we had to rely on a different approach.

By depositing the atomically thin 2D crystal on top of a microscopically small wire, a thousand times thinner than a human hair, we created a small, elongated dent in the two-dimensional material, slightly pulling apart the atoms in the two-dimensional crystal and inducing strain in the material. For excitons, this dent is much like a pipe for water and once trapped inside, they are bound to move along the pipe, realizing quasi one-dimensional transport of excitons.”

This advancement holds possibilities for new devices.



Topography of the two-dimensional crystal on top of the microscopically small wire indicated by dashed lines. Excitons freely move along the wire-induced dent, but cannot escape it in the perpendicular direction.

“Manipulating the motion of excitons at the nanoscale realizes an important step towards excitonic devices,” noted Dirnberger. “Platforms based on two-dimensional semiconductor transition-metal dichalcogenides offer an interesting new approach called straintronics.”

Possible outcomes include innovative devices based on excitons that operate at room temperature and could replace certain tasks performed by contemporary transistor technology.

Read the [original article](#) on The City College of New York.